502540773 10/22/2013

PATENT ASSIGNMENT COVER SHEET

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SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

CONVEYING PARTY DATA

Name	Execution Date
KUO-CHENG CHING	10/15/2013
GUAN-LIN CHEN	10/16/2013
CHAO-HSIUNG WANG	10/15/2013
CHI-WEN LIU	10/15/2013

RECEIVING PARTY DATA

Name:	TAIWAN SEMICONDUCTOR MANUFACTURING COMPANY, LTD.
Street Address:	NO. 8, LI-HSIN ROAD 6
Internal Address:	SCIENCE-BASED INDUSTRIAL PARK
City:	HSIN-CHU
State/Country:	TAIWAN
Postal Code:	300-77

PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	14055417

CORRESPONDENCE DATA

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NAME OF SUBMITTER:	TERESA M. PRICE

PATENT REEL: 031451 FRAME: 0129 P \$40.00 140554

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Signature:	/Teresa M. Price/	
Date:	10/22/2013	
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PATENT REEL: 031451 FRAME: 0130

Docket No.: 2013-1041/24061.2649

Customer No.: 000042717

ASSIGNMENT

WHEREAS, we,

(1)	Kuo-Cheng Ching	of	5F., No.8-3, Guangming 9th Rd. Zhubei City, Hsinchu County 302, Taiwan R.O.C.
(2)	Guan-Lin Chen	of	No.168, Park Ave. II Hsinchu Science Park, Hsin-Chu City Taiwan R.O.C.
(3)	Chao-Hsiung Wang	of	5F-1, No.29, Jianzhong 1st Rd Hsin-Chu City, 300 Taiwan R.O.C.
(4)	Chi-Wen Liu	of	3F, No. 561, Nan-Da Rd. Hsin-Chu City, Taiwan R.O.C.

have invented certain improvements in

FINFET WITH BURIED INSULATOR LAYER AND METHOD FOR FORMING

For which we have filed an application for Letters Patent of the United States of America on October 16, 2013, as U.S. Serial No. 14/055,417; and

WHEREAS, we authorize the attorney of record to update this document to include Patent Office information as deemed necessary (i.e., filing date, serial number, etc.);

WHEREAS, Taiwan Semiconductor Manufacturing Company, Ltd., ("TSMC"), No. 8, Li-Hsin Rd. 6, Science-Based Industrial Park Hsin-Chu, Taiwan 300-77, Republic of China. is desirous of obtaining the entire right, title, and interest in, to and under the said invention and the said application in the United States of America and in any and all countries foreign thereto;

NOW, THEREFORE, for good and valuable consideration, the receipt and sufficiency of which is hereby acknowledged, and other good and valuable consideration, we have sold, assigned, transferred and set over, and by these presents do hereby sell, assign, transfer and set over, unto the said TSMC, its successors, legal representatives, and assigns, the entire right, title, and interest in, to and under the said invention, and the said application, and all divisional, renewal, substitutional, and continuing applications thereof, and all Letters Patent of the United States of America which may be granted thereon and all reissues and extensions thereof, and all applications for Letters Patent which may be filed for said invention in any country or countries foreign to the United States of America, and all extensions, renewals, and reissues thereof, and all prior patents and patent applications from which a filing priority of the above-described patent application may be obtained, including the right to collect past damages; and we hereby authorize and request the Commissioner of Patents of the United States of America, and any official of any country or countries foreign to the United States of America, whose duty it is to issue patents on applications as aforesaid, to issue all Letters Patent for said invention to the said TSMC, its successors, legal representatives and assigns, in accordance with the terms of this instrument.

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AND WE HEREBY covenant that we have full right to convey the entire interest herein assigned, and that we have not executed, and will not execute, any agreement in conflict herewith.

AND WE HEREBY further covenant and agree that we will communicate to said TSMC, its successors, legal representatives and assigns, any facts known to us respecting said invention, and testify in any legal proceedings, sign all lawful papers, execute all divisional, renewal, substitutional, continuing, and reissue applications, make all rightful declarations and/or oaths and generally do everything possible to aid the said TSMC, its successors, legal representatives and assigns, to obtain and enforce proper patent protection for said invention in all countries.

Inventor Name:	Kuo-Cheng Ching	
Residence Address:	5F., No.8-3, Guangming 9th Ro Zhubei City, Hsinchu County 3	
Dated: 2013/10/		Inventor Signature
Inventor Name:	Guan-Lin Chen	
Residence Address:	No.168, Park Ave. II Hsinchu Science Park, Hsin-Ch	u City, Taiwan R.O.C.
Dated: 2013/10/	16	Inventor Signature
Inventor Name:	Chao-Hsiung Wang	
Residence Address:	5F-1, No.29, Jianzhong 1st Rd Hsin-Chu City, 300 Taiwan R.0	D.C.
Dated:	115	Inventor Signature
Inventor Name:	Chi-Wen Liu	
Residence Address: Dated: 2017/10	3F, No. 561, Nan-Da Rd. Hsin-Chu City, Taiwan R.O.C.	Chi-Wen LL Inventor Signature

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